Description

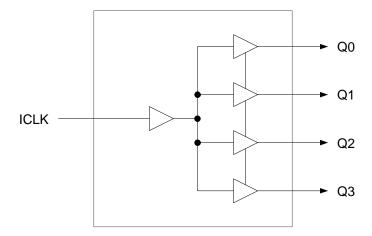
The 524S is a low skew, single input to four output, clock buffer. The 524S has best in class additive phase Jitter of sub 50 fsec.

IDT makes many non-PLL and PLL based low skew output devices as well as Zero Delay Buffers to synchronize clocks. Contact us for all of your clocking needs.

Features

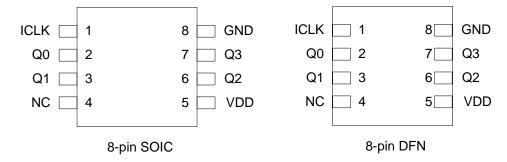
- Low additive phase jitter RMS: 50fs
- Extremely low skew outputs (50ps)
- Low cost clock buffer
- Packaged in 8-pin SOIC and 8-pin DFN, Pb-free
- Input/Output clock frequency up to 200 MHz
- Non-inverting output clock
- Ideal for networking clocks
- Operating Voltages: 1.8V to 3.3V
- Advanced, low power CMOS process
- Extended temperature range (-40°C to +105°C)

Block Diagram





Pin Assignments



Pin Descriptions

Pin Number	Pin Name	Pin Type	Pin Description				
1	ICLK	Input	Clock input.				
2	Q0	Output	Clock output 0.				
3	Q1	Output	Clock output 1.				
4	NC	-	No connect.				
5	VDD	Power	Connect to +1.8V, +2.5 V, or +3.3 V.				
6	Q2	Output	Clock Output 2.				
7	Q3	Output	Clock Output 3.				
8	GND	Power	Connect to ground.				

External Components

A minimum number of external components are required for proper operation. A decoupling capacitor of $0.01\mu F$ should be connected between VDD on pin 5 and GND on pin 8, as close to the device as possible. A 33Ω series terminating resistor may be used on each clock output if the trace is longer than 1 inch.

To achieve the low output skew that the 524S is capable of, careful attention must be paid to board layout. Essentially, all four outputs must have identical terminations, identical loads and identical trace geometries. If they do not, the output skew will be degraded. For example, using a 30Ω series termination on one output (with 33Ω on the others) will cause at least 15 ps of skew.



Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 524S. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD	3.465V
Outputs	-0.5 V to VDD+0.5 V
ICLK	3.465V
Ambient Operating Temperature (extended)	-40° to +105°C
Storage Temperature	-65° to +150°C
Junction Temperature	125°C
Soldering Temperature	260°C

Recommended Operation Conditions

Parameter	Min.	Тур.	Max.	Units
Ambient Operating Temperature (extended)	-40		+105	°C
Power Supply Voltage (measured in respect to GND)	+1.71		+3.465	V



DC Electrical Characteristics

(VDD = 1.8V, 2.5V, 3.3V)

VDD=1.8V ±5%, Ambient temperature -40° to +105°C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		1.71		1.89	V
Input High Voltage, ICLK	V _{IH}	Note 1	0.7xVDD		VDD	V
Input Low Voltage, ICLK	V _{IL}	Note 1			0.3xVDD	V
Output High Voltage	V _{OH}	I _{OH} = -10 mA	1.3			V
Output Low Voltage	V _{OL}	I _{OL} = 10 mA			0.35	V
Operating Supply Current	IDD	No load, 135 MHz		16		mA
Nominal Output Impedance	Z _O			17		Ω
Input Capacitance	C _{IN}	ICLK		5		pF

Notes: 1. Nominal switching threshold is VDD/2

VDD=2.5 V ±5%, Ambient temperature -40° to +105°C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		2.375		2.625	V
Input High Voltage, ICLK	V _{IH}	Note 1	0.7xVDD		VDD	V
Input Low Voltage, ICLK	V _{IL}	Note 1			0.3xVDD	V
Output High Voltage	V _{OH}	I _{OH} = -16 mA	1.8			V
Output Low Voltage	V _{OL}	I _{OL} = 16 mA			0.5	V
Operating Supply Current	IDD	No load, 135 MHz		18		mA
Nominal Output Impedance	Z _O			17		Ω
Input Capacitance	C _{IN}	ICLK		5		pF

VDD=3.3 V ±5%, Ambient temperature -40° to +105°C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		3.15		3.45	V
Input High Voltage, ICLK	V _{IH}	Note 1	0.7xVDD		VDD	V
Input Low Voltage, ICLK	V _{IL}	Note 1			0.3xVDD	V
Output High Voltage	V _{OH}	I _{OH} = -25 mA	2.2			V
Output Low Voltage	V _{OL}	I _{OL} = 25 mA			0.7	V
Operating Supply Current	IDD	No load, 135 MHz		22		mA
Nominal Output Impedance	Z _O			17		Ω
Input Capacitance	C _{IN}	ICLK		5		pF



AC Electrical Characteristics

(VDD = 1.8V, 2.5V, 3.3V)

VDD = 1.8V ±5%, Ambient Temperature -40° to +105°C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Frequency			0		200	MHz
Output Rise Time	t _{OR}	0.36 to 1.44 V, C _L =5 pF		0.6	1.0	ns
Output Fall Time	t _{OF}	1.44 to 0.36 V, C _L =5 pF		0.6	1.0	ns
Propagation Delay		Note 1	1.5	2	4	ns
Buffer Additive Phase Jitter, RMS		125MHz, Integration Range: 12kHz-20MHz			0.05	ps
Output to Output Skew		Rising edges at VDD/2, Note 2			65	ps
Device to Device Skew		Rising edges at VDD/2			200	ps
Start-up Time	t _{START-UP}	Part start-up time for valid outputs after VDD ramp-up			2	ms

VDD = 2.5 V ±5%, Ambient Temperature -40° to +105°C, unless stated otherwise

Parameter	Symbol	Conditions		Тур.	Max.	Units
Input Frequency			0		200	MHz
Output Rise Time	t _{OR}	0.5 to 2.0 V, C _L =5 pF		0.6	1.0	ns
Output Fall Time	t _{OF}	2.0 to 0.5 V, C _L =5 pF		0.6	1.0	ns
Propagation Delay		Note 1	1.8	2.5	4.5	ns
Buffer Additive Phase Jitter, RMS		125MHz, Integration Range: 12kHz-20MHz			0.05	ps
Output to Output Skew		Rising edges at VDD/2, Note 2			65	ps
Device to Device Skew		Rising edges at VDD/2			200	ps
Start-up Time	t _{START-UP}	Part start-up time for valid outputs after VDD ramp-up			2	ms

VDD = 3.3 V ±5%, Ambient Temperature -40° to +105°C, unless stated otherwise

Parameter	rameter Symbol Conditions		Min.	Тур.	Max.	Units	
Input Frequency			0		200	MHz	
Output Rise Time	t _{OR}	0.66 to 2.64 V, C _L =5 pF		0.6	1.0	ns	
Output Fall Time	t _{OF}	2.64 to 0.66 V, C _L =5 pF		0.6	1.0	ns	
Propagation Delay		Note 1	1.5	2	4	ns	
Buffer Additive Phase Jitter, RMS		125MHz, Integration Range: 12kHz-20MHz			0.05	ps	
Output to Output Skew		Rising edges at VDD/2, Note 2			65	ps	
Device to Device Skew		Rising edges at VDD/2			200	ps	
Start-up Time	t _{START-UP}	Part start-up time for valid outputs after VDD ramp-up			2	ms	

Notes:

- 1. With rail to rail input clock
- 2. Between any 2 outputs with equal loading.
- 3. Duty cycle on outputs will match incoming clock duty cycle. Consult IDT for tight duty cycle clock generators.



Phase Noise Plots

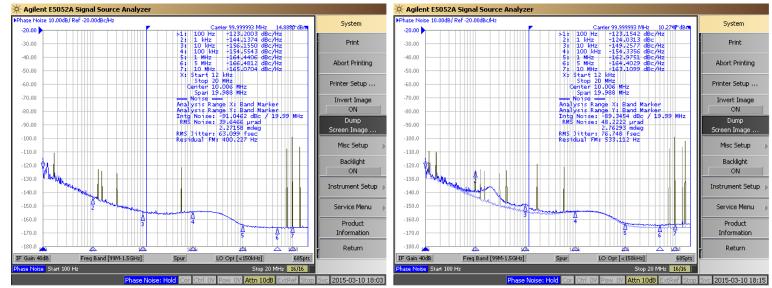
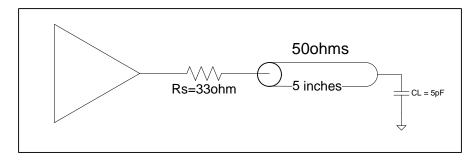


Figure 1. 524S Reference Phase Noise 63fs (12kHz to 20MHz)

Figure 2. 524S Output Phase Noise 76fs (12kHz to 20MHz)

The phase noise plots above show the low Additive Jitter of the 524S high-performance buffer. With an integration range of 12kHz to 20MHz, the reference input has about 63fs of RMS phase jitter while the output of 524S has about 76fs of RMS phase jitter. This results in a low Additive Phase Jitter of only 42fs.

Test Load and Circuit

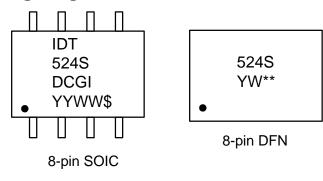




Thermal Characteristics (8SOIC)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to Ambient	$\theta_{\sf JA}$	Still air		150		°C/W
	θ_{JA}	1 m/s air flow		140		°C/W
	θ_{JA}	3 m/s air flow		120		°C/W
Thermal Resistance Junction to Case	θЈС			40		°C/W

Marking Diagrams

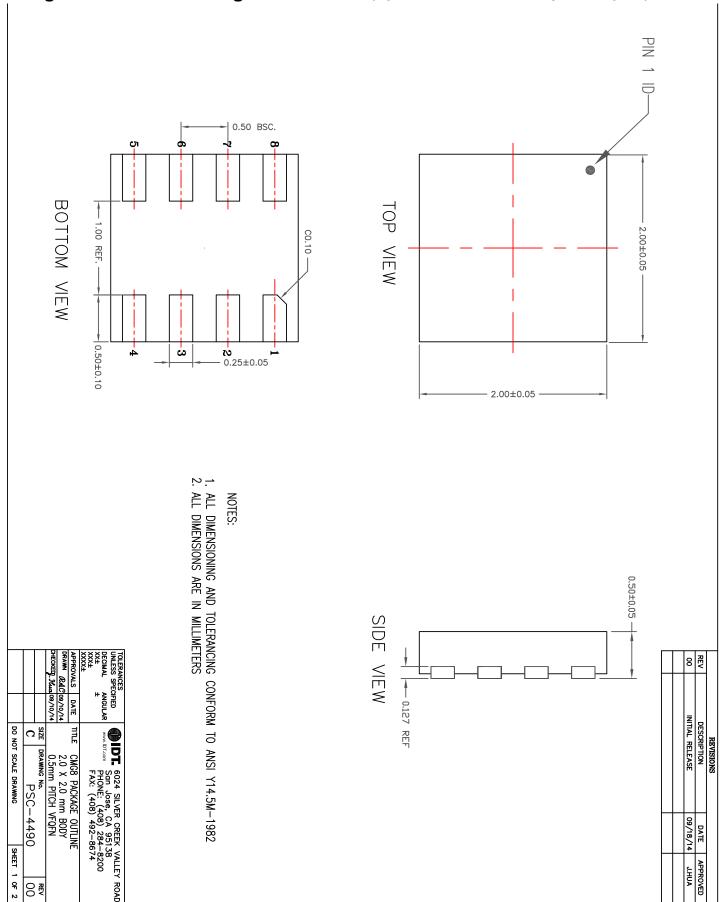


Notes:

- 1. "**" is the lot number.
- 2. "YYWW" or "YW" are the last digits of the year and week that the part was assembled.
- 3 "G" denotes RoHS compliant package.
- 4. "\$" denotes the mark code.
- 5. "I" denotes extended temperature range device.



Package Outline and Package Dimensions (8-pin DFN, 2mm x 2mm Body, 0.5mm pitch)





Package Outline and Package Dimensions, cont. (8-pin DFN, 2mm x 2mm Body, 0.5mm pitch)

7351B GENERIC REQUIREMENT FOR

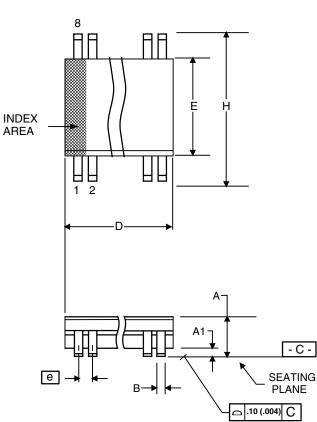
RECOMMENDED LAND PATTERN DIMENSION

	-	30	←	↓	
4	3	80	1	.95	2.
On .	6	50	8		\frac{1}{5}

			CHECKED	DRAWN RAC	APPROVALS	TOLERANCES UNLESS SPECIFIED DECIMAL ANGU XX± ± XXXX± XXXX± XXXXX±
				RAC 09/10/14	DATE	CIFIED ANGULAR ±
DO NO	С	SIZE			를	WWW.IDT.com
DO NOT SCALE DRAWING	PSC-4490	DRAWING No.	0.5 mm PITCH VFQFN	2.0 X 2.0 mm BODY	CMG8 PACKAGE OUTLINE	● IDT. 6024 SILVER CREEK VALLEY ROAD San Jose, CA 95138 PHONE: (408) 284-8200 FAX: (408) 492-8674
SHEET 2 OF 2					[1]	VALLEY 38 -8200 674
유 2	00	REV				ROAD

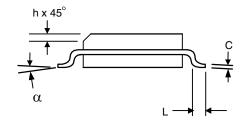


Package Outline and Package Dimensions (8-pin SOIC, 150 Mil. Narrow Body)



	Millimeters		Inches*	
Symbol	Min	Max	Min	Max
Α	1.35	1.75	.0532	.0688
A1	0.10	0.25	.0040	.0098
В	0.33	0.51	.013	.020
С	0.19	0.25	.0075	.0098
D	4.80	5.00	.1890	.1968
E	3.80	4.00	.1497	.1574
е	1.27 BASIC		0.050 BASIC	
Н	5.80	6.20	.2284	.2440
h	0.25	0.50	.010	.020
L	0.40	1.27	.016	.050
а	0°	8°	0°	8°

^{*}For reference only. Controlling dimensions in mm.



Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
524SDCGI	see page 7	Tubes	8-pin SOIC	-40° to +105°C
524SDCGI8		Tape and Reel	8-pin SOIC	-40° to +105°C
524SCMGI		Cut Tape	8-pin DFN	-40° to +105°C
524SCMGI8		Tape and Reel	8-pin DFN	-40° to +105°C

[&]quot;G" after the two-letter package code denotes Pb-Free configuration, RoHS compliant.



Revision History

Rev.	Date	Originator	Description of Change
Α	A 03/18/15 B. Chandhoke Initial release.		Initial release.



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TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

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